## TVS Diodes

## 1KE1G3V0C ~ 1KE1G5V0C

- Features
- Low Clamping Voltage.
- Small Body Outline Dimensions..
- Low Leakage
- ESD Rating of Class 3 ( $>16 \mathrm{kV}$ ) per Human Body
- IEC61000-4-2 Level 4 ESD Protection IEC61000-

4-4 Level 4 EFT Protection


Absolute Maximum Ratings $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| IEC 61000-4-2(ESD) |  | $\pm 30$ | KV |
|  |  | $\pm 30$ |  |
| IEC 61000-4-4(EFT) |  | 40 | A |
| ESD Voltage Per Human Body Model |  | 16 | KV |
| Total Power Dissipation on FR-4 Board *1 | $\mathrm{P}_{\mathrm{D}}$ | 500 | mW |
| Junction Temperature | TJ | 150 | C |
| Storage Temperature range | Tstg | -55 to +150 |  |
| Lead Solder Temperature - Maximum (10 Second Duration) | TL | 260 |  |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
*1. FR-4 printed circuit board, single-sided copper, mounting pad 1 cm²

## TVS Diodes

## 1KE1G3V0C ~ 1KE1G5V0C

■ Electrical Characteristics $\mathrm{Ta}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter |
| :---: | :--- |
| $\mathrm{I}_{\mathrm{PP}}$ | Maximum Reverse Peak Pulse Current |
| $\mathrm{V}_{\mathrm{C}}$ | Clamping Voltage @ $\mathrm{I}_{\mathrm{PP}}$ |
| $\mathrm{V}_{\mathrm{RWM}}$ | Working Peak Reverse Voltage |
| $\mathrm{I}_{\mathrm{R}}$ | Maximum Reverse Leakage Current @ $\mathrm{V}_{\mathrm{RWM}}$ |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown Voltage @ $\mathrm{I}_{\mathrm{T}}$ |
| $\mathrm{I}_{\mathrm{T}}$ | Test Current |
| C | Capacitance @ $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ and $\mathrm{f}=1.0 \mathrm{MHz}$ |



Electrical Characteristics Ta $=25^{\circ} \mathrm{C}$

| Device** | Device Marking | $\mathrm{V}_{\text {RWM }}$ (V) | $\begin{gathered} \mathrm{I}_{\mathrm{R}}(\mathrm{nA}) \\ @ \mathrm{~V}_{\mathrm{RWM}} \end{gathered}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{BR}}(\mathrm{~V}) @ I_{\mathrm{T}} \\ & (\text { Note 2) } \end{aligned}$ | $\mathrm{I}_{\mathrm{T}}$ | $\begin{gathered} \mathrm{V}_{\mathrm{C}}(\mathrm{~V}) \\ @ \mathrm{I}_{\mathrm{PP}}=5.0 \mathrm{~A}^{\dagger} \end{gathered}$ | $\mathrm{V}_{\mathrm{C}}(\mathrm{V})$ <br> @ Max $\mathrm{IPP}^{\dagger}$ | $\mathrm{IPp}^{(A)}{ }^{\dagger}$ | $\begin{aligned} & \mathrm{P}_{\mathrm{pk}} \\ & (\mathrm{~W})^{\dagger} \end{aligned}$ | C (pF) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Max | Max | Min | mA | Typ | Max | Max | Max | Typ |
| 1KE1G3V0C | 3C | 3.0 | 100 | 4.0 | 1.0 | 7.5 | 12.9 | 11.0 | 137 | 125 |
| 1KE1G3V3C | 3D | 3.3 | 100 | 5.0 | 1.0 | 8.4 | 14.1 | 11.2 | 158 | 105 |
| 1KE1G5V0C | 5C | 5.0 | 100 | 5.6 | 1.0 | 11.6 | 18.6 | 9.4 | 174 | 80 |

**Other voltages available upon request.
1.Surge current waveform per Figure5.
2.VBR is measured with a pulse test current IT at an ambient temperature of $25^{\circ} \mathrm{C}$
3.For test procedure see Fugures 3 and 4


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV contact per IEC 61000-4-2


## TVS Diodes

## 1KE1G3V0C ~ 1KE1G5V0C

IEC 61000-4-2 Spec.

| Level | Test Volt- <br> age (kV) | First Peak <br> Current <br> $(\mathbf{A )}$ | Current at <br> $\mathbf{3 0} \mathbf{n s}(\mathbf{A )}$ | Current at <br> $\mathbf{6 0} \mathbf{n s}(\mathbf{A )}$ |
| :---: | :---: | :---: | :---: | :---: |
| 1 | 2 | 7.5 | 4 | 2 |
| 2 | 4 | 15 | 8 | 4 |
| 3 | 6 | 22.5 | 12 | 6 |
| 4 | 8 | 30 | 16 | 8 |



Figure 3. IEC61000-4-2 Spec


## ESD Voltage Clamping

For sensitive circuit elements ,it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level.


Figure 5. $8 \times 20 \mu$ s Pulse Waveform

## TVS Diodes

## 1KE1G3V0C ~ 1KE1G5V0C

Package Outline Dimensions (SOD-523)


Note: Dimensions are exclusive of Burrs, Mold Flash \& Tie Bar extrusions.

The Recommended Mounting Pad Size


